# **14-Bit Binary Counter and Oscillator**

The MC14060B is a 14–stage binary ripple counter with an on–chip oscillator buffer. The oscillator configuration allows design of either RC or crystal oscillator circuits. Also included on the chip is a reset function which places all outputs into the zero state and disables the oscillator. A negative transition on Clock will advance the counter to the next state. Schmitt trigger action on the input line permits very slow input rise and fall times. Applications include time delay circuits, counter controls, and frequency dividing circuits.

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}.$ 

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$  or  $V_{DD}$ ). Unused outputs must be left open.

#### **Features**

- Fully Static Operation
- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 V to 18 V
- Capable of Driving Two Low-power TTL Loads or One Low-power Schottky TTL Load Over the Rated Temperature Range
- Buffered Outputs Available from Stages 4 Through 10 and 12 Through 14
- Common Reset Line
- Pin-for-Pin Replacement for CD4060B
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

#### MAXIMUM RATINGS (Voltages Referenced to V<sub>SS</sub>)

	, 0	•	
Symbol	Parameter	Value	Unit
V <sub>DD</sub>	DC Supply Voltage Range	-0.5 to +18.0	V
V <sub>in</sub> , V <sub>out</sub>	Input or Output Voltage Range (DC or Transient)	-0.5 to V <sub>DD</sub> +0.5	V
I <sub>in</sub> , I <sub>out</sub>	Input or Output Current (DC or Transient) per Pin	±10	mA
P <sub>D</sub>	Power Dissipation, per Package (Note 1)	500	mW
T <sub>A</sub>	Ambient Temperature Range	-55 to +125	°C
T <sub>stg</sub>	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature (8 Second Soldering)	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Packages: -7.0 mW/°C from 65°C To 125°C.



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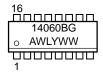
SOIC-16 D SUFFIX CASE 751B SOEIAJ-16 F SUFFIX CASE 966

TSSOP-16 DT SUFFIX CASE 948F

#### **PIN ASSIGNMENT**

Q12 [	1 ●	16	þ	$V_{DD}$
Q13 [	2	15	þ	Q10
Q14 [	3	14	þ	Q8
Q6 [	4	13	þ	Q9
Q5 [	5	12	þ	RESET
Q7 [	6	11	þ	CLOCK
Q4 [	7	10	þ	OUT 1
V <sub>SS</sub> [	8	9	þ	OUT 2

#### MARKING DIAGRAMS





SOIC-16

SOEIAJ-16



TSSOP-16

A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week G or = Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

**Table 1. Truth Table** 

Clock	Reset	Output State
エイト	LLΗ	No Change Advance to Next State All Outputs are Low

X = Don't Care

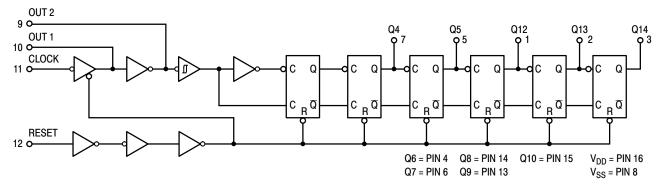


Figure 1. Logic Diagram

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MC14060BDG	SOIC-16 (Pb-Free)	48 Units / Rail
NLV14060BDG*	SOIC-16 (Pb-Free)	48 Units / Rail
MC14060BDR2G	SOIC-16 (Pb-Free)	2500 / Tape & Reel
NLV14060BDR2G*	SOIC-16 (Pb-Free)	2500 / Tape & Reel
MC14060BDTR2G	TSSOP-16 (Pb-Free)	2500 / Tape & Reel
NLV14060BDTR2G*	TSSOP-16 (Pb-Free)	2500 / Tape & Reel
MC14060BFELG	SOEIAJ-16 (Pb-Free)	2000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

#### **ELECTRICAL CHARACTERISTICS** (Voltages Referenced to V<sub>SS</sub>)

			-5	5°C		25°C		125°C		
Symbol	Characteristic	V <sub>DD</sub> Vdc	Min	Max	Min	Typ (Note 2)	Max	Min	Max	Unit
V <sub>OL</sub>	Output Voltage "0" Level $V_{in} = V_{DD}$ or 0	5.0 10 15	- - -	0.05 0.05 0.05	- - -	0 0 0	0.05 0.05 0.05	- - -	0.05 0.05 0.05	V
V <sub>OH</sub>	$V_{in} = 0$ or $V_{DD}$ "1" Level	5.0 10 15	4.95 9.95 14.95	- - -	4.95 9.95 14.95	5.0 10 15	- - -	4.95 9.95 14.95	- - -	V
V <sub>IL</sub>	Input Voltage "0" Level $(V_O = 4.5 \text{ or } 0.5 \text{ V})$ $(V_O = 9.0 \text{ or } 1.0 \text{ V})$ $(V_O = 13.5 \text{ or } 1.5 \text{ V})$	5.0 10 15	- - -	1.5 3.0 4.0	- - -	2.25 4.50 6.75	1.5 3.0 4.0	- - -	1.5 3.0 4.0	V
V <sub>IH</sub>	$(V_O = 0.5 \text{ or } 4.5 \text{ V})$ "1" Level $(V_O = 1.0 \text{ or } 9.0 \text{ V})$ $(V_O = 1.5 \text{ or } 13.5 \text{ V})$	5.0 10 15	3.5 7.0 11.0	- - -	3.5 7.0 11.0	2.75 5.50 8.25	- - -	3.5 7.0 11.0	- - -	V
V <sub>IL</sub>		5.0 10 15	- - -	1.0 2.0 2.5	_ _ _	2.25 4.50 6.75	1.0 2.0 2.5	- - -	1.0 2.0 2.5	Vdc
V <sub>IH</sub>	$(V_O = 0.5 \text{ Vdc})$ "1" Level $(V_O = 1.0 \text{ Vdc})$ $(V_O = 1.5 \text{ Vdc})$	5.0 10 15	4.0 8.0 12.5	- - -	4.0 8.0 12.5	2.75 5.50 8.25	- - -	4.0 8.0 12.5	- - -	Vdc
I <sub>OH</sub>	Output Drive Current (V <sub>OH</sub> = 2.5 V) (Except Source (V <sub>OH</sub> = 4.6 V) Pins 9 and 10) (V <sub>OH</sub> = 9.5 V) (V <sub>OH</sub> = 13.5 V)	5.0 5.0 10 15	-3.0 -0.64 -1.6 - 4.2	- - -	-2.4 -0.51 -1.3 -3.4	-4.2 -0.88 -2.25 -8.8	- - - -	- 1.7 - 0.36 - 0.9 - 2.4	- - - -	mA
I <sub>OL</sub>	$(V_{OL} = 0.4 \text{ V})$ Sink $(V_{OL} = 0.5 \text{ V})$ $(V_{OL} = 1.5 \text{ V})$	5.0 10 15	0.64 1.6 4.2	- - -	0.51 1.3 3.4	0.88 2.25 8.8	- - -	0.36 0.9 2.4	- - -	mA
l <sub>in</sub>	Input Current	15	_	±0.1	-	±0.00001	±0.1	_	±1.0	μΑ
C <sub>in</sub>	Input Capacitance (V <sub>in</sub> = 0)	-	-	-	-	5.0	7.5	_	-	pF
I <sub>DD</sub>	Quiescent Current (Per Package)	5.0 10 15	- - -	5.0 10 20	- - -	0.005 0.010 0.015	5.0 10 20	- - -	150 300 600	μΑ
lτ	Total Supply Current (Notes 3, 4) (Dynamic plus Quiescent, Per Package) (C <sub>L</sub> = 50 pF on all outputs, all buffers switching)	5.0 10 15			$I_{T} = (0$	.25 μA/kHz) .54 μA/kHz) .85 μA/kHz)	f + I <sub>DD</sub>			μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

3. The formulas given are for the typical characteristics only at 25°C.

4. To calculate total supply current at loads other than 50 pF: I<sub>T</sub>(C<sub>L</sub>) = I<sub>T</sub>(50 pF) + (C<sub>L</sub> – 50) Vfk where: I<sub>T</sub> is in μA (per package), C<sub>L</sub> in pF, V = (V<sub>DD</sub> – V<sub>SS</sub>) in volts, f in kHz is input frequency, and k = 0.002.

## SWITCHING CHARACTERISTICS ( $C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}$ )

Symbol	Characteristic	V <sub>DD</sub> Vdc	Min	Typ (Note 5)	Max	Unit
t <sub>TLH</sub>	Output Rise Time (Counter Outputs)	5.0 10 15	- - -	40 25 20	200 100 80	ns
t <sub>THL</sub>	Output Fall Time (Counter Outputs)	5.0 10 15	- - -	50 30 20	200 100 80	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Time Clock to Q4	5.0 10 15	- - -	415 175 125	740 300 200	ns
	Clock to Q14	5.0 10 15	- - -	1.5 0.7 0.4	2.7 1.3 1.0	μs
t <sub>wH</sub>	Clock Pulse Width	5.0 10 15	100 40 30	65 30 20	- - -	ns
$f_{\Phi}$	Clock Pulse Frequency	5.0 10 15	- - -	5 14 17	3.5 8 12	MHz
t <sub>TLH</sub> t <sub>THL</sub>	Clock Rise and Fall Time	5.0 10 15		No Limit		ns
t <sub>w</sub>	Reset Pulse Width	5.0 10 15	120 60 40	40 15 10	_ _ _	ns
t <sub>PHL</sub>	Propagation Delay Time Reset to On	5.0 10 15	- - -	170 80 60	350 160 100	ns

<sup>5.</sup> Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

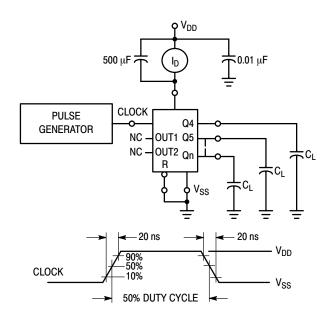


Figure 1. Power Dissipation Test Circuit and Waveform

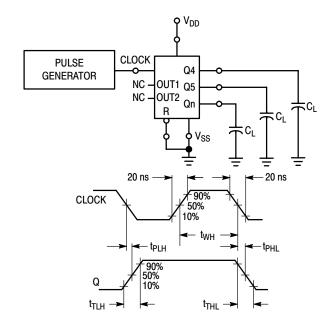
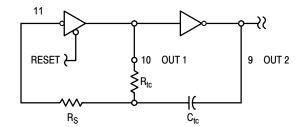


Figure 2. Switching Time Test Circuit and Waveforms



$$f \approx \frac{1}{2.3 \, R_{tc} C_{tc}}$$
if 1 kHz  $\leq$  f  $\leq$  100 kHz
and 2R<sub>tc</sub>  $<$  R<sub>S</sub>  $<$  10R<sub>tc</sub>

(f in Hz, R in ohms, C in farads)

The formula may vary for other frequencies. Recommended maximum value for the resistors in 1  $M\Omega.$ 

Figure 3. Oscillator Circuit Using RC Configuration

#### TYPICAL RC OSCILLATOR CHARACTERISTICS

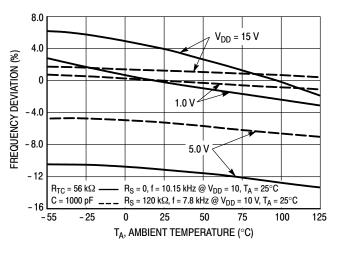


Figure 4. RC Oscillator Stability

 $V_{DD} = 10 V$ 50 f, OSCILLATOR FREQUENCY (kHz) f AS A FUNCTION 20 OF R<sub>TC</sub> (C = 1000 pF)10  $\left(R_S\approx 2R_{TC}\right)$ 5 f AS A FUNCTION 2 OF C  $(R_{TC} = 56 \text{ k}\Omega)$  $(R_S = 120 \text{ k})$ 0.5 0.2 1.0 k 10 k 100 k 1.0 M R<sub>TC</sub>, RESISTANCE (OHMS) 0.0001 0.01 0.1 C, CAPACITANCE (µF)

Figure 5. RC Oscillator Frequency as a Function of  $R_{TC}$  and C

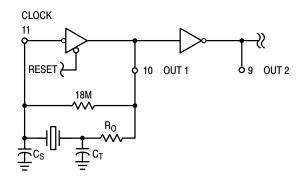


Figure 6. Typical Crystal Oscillator Circuit

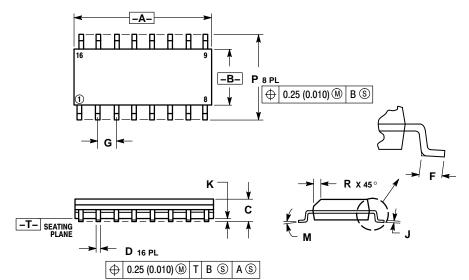
Table 2. Typical Data for Crystal Oscillator Circuit

Characteristic	500 kHz Circuit	32 kHz Circuit	Unit
Crystal Characteristics Resonant Frequency Equivalent Resistance, R <sub>S</sub>	500 1.0	32 6.2	kHz kΩ
External Resistor/Capacitor Values RO CT CS	47 82 20	750 82 20	kΩ pF pF
Frequency Stability Frequency Changes as a Function of V <sub>DD</sub> (T <sub>A</sub> = 25°C) V <sub>DD</sub> Change from 5.0 V to 10 V V <sub>DD</sub> Change from 10 V to 15 V Frequency Change as a Function of Temperature (V <sub>DD</sub> = 10 V) T <sub>A</sub> Change from - 55°C to +25°C Complete Oscillator (Note 6) T <sub>A</sub> Change from + 25°C to +125°C Complete Oscillator (Note 6) (Note 6)	+6.0 +2.0 +100 -160	+2.0 +2.0 +120 -560	ppm ppm

<sup>6.</sup> Complete oscillator includes crystal, capacitors, and resistors.

#### **PACKAGE DIMENSIONS**

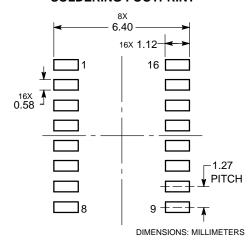
SOIC-16 **D SUFFIX** CASE 751B-05 ISSUE K



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050	BSC
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

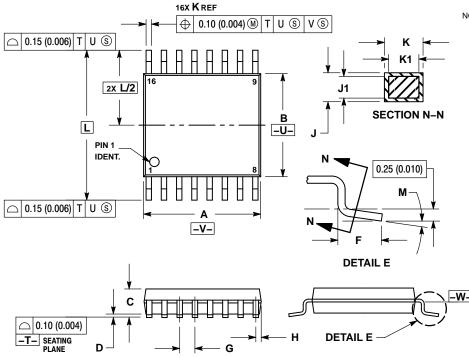
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#### **PACKAGE DIMENSIONS**

#### TSSOP-16 **DT SUFFIX** CASE 948F **ISSUE B**



- NOTES:

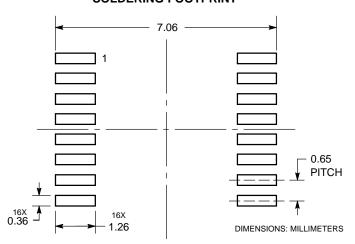
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETER.

  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCED A 15 (
  - INCLUPTUSM ON GATE BORNS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL
  - NOT EXCEED 0.25 (0.010) PER SIDE.
    5. DIMENSION K DOES NOT INCLUDE
    DAMBAR PROTRUSION. ALLOWABLE
    DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K
    DIMENSION AT MAXIMUM MATERIAL CONDITION.
  - 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	BSC	0.026 BSC	
Н	0.18	0.28	0.007	0.011
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
Κ	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
Г	6.40 BSC		0.252	BSC
М	0°	8°	0°	8 °

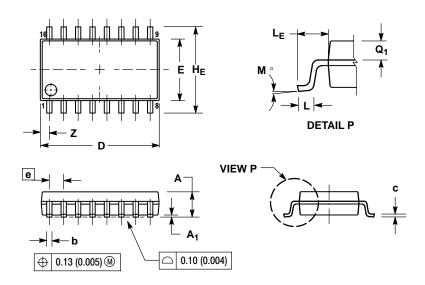
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#### **PACKAGE DIMENSIONS**

SOEIAJ-16 F SUFFIX CASE 966 ISSUE A



#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
- 2. OWN HOLLING DIMENSION. WILLING LIED.
  3. DIMENSIONS D AND E DO NOT INCLUDE
  MOLD FLASH OR PROTRUSIONS AND ARE
  MEASURED AT THE PARTING LINE. MOLD FLASH
  OR PROTRUSIONS SHALL NOT EXCEED 0.15
  (0.006) PER SIDE.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- REFERENCE UNLT.

  S. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	-	2.05		0.081
A <sub>1</sub>	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
С	0.10	0.20	0.007	0.011
D	9.90	10.50	0.390	0.413
Ε	5.10	5.45	0.201	0.215
е	1.27 BSC		0.050	BSC
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0 °	10 °	0 °	10°
$Q_1$	0.70	0.90	0.028	0.035
Z		0.78		0.031

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